High Power LED Series

LH508C ECO General



High efficacy and lumen makes

The LH508C ECO suitable for Streetlight and High-bay applications

Features & Benefits

- Operates at a maximum current of up to 220mA
- Uniform light distribution under any beam angle
- Color binning @ 85°C









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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Operating Temperature	T_{opr}	-40 ~ +105	°C	
Storage Temperature	T_{stg}	-40 ~ +100	°C	-
LED Junction Temperature	Tj	125	°C	-
Forward Current	I _F	220	mA	-
Peak Pulse Forward Current	I _{FP}	300	mA	Duty cycle≤1/10, pulse width 10ms
Soldering Temperature		260 <10	°C	-
Electrostatic Discharge Withstand Voltage(HBM)	ESD(HBM)	±2	kV	-

b) Electro-optical Characteristics ($I_{\textrm{F}}$ = 160 mA, $T_{\textrm{j}}$ = 25°C $\,$)

Item	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V _F)	V	XE	23.5	-	25.5
Color Dandering Index (D. V. DO		3	70 / -50	-	-
Color Rendering Index (R _a) / R9	-	5	80 / 0		
Thermal Resistance (junction to chip point)	°C/W		-	3	-
Beam Angle	0			120	

Notes:

Samsung maintains measurement tolerance of: luminous flux = ± 7 %, forward voltage = ± 5 %, CRI = ± 3 , R9 = ± 6.5

c) Luminous Flux Characteristics (I_F = 160 mA)

CRI (R _a)	Nominal	Flux		Flux @ T」= 25 °C (Im)
Min.	CCT (K)	Rank	Flux @ Flux & Fl	Тур.	Max.
	2200K	A4	560		
	2700K	A 4	620		
	3000K	A4	640		
70	3500K	A4	650		
70	4000K	A4	660		
	5000K	A4	660		
	5700K	A4	650		
	6500K	A4	640		
	2200K	A4	470		
	2700K	A4	550		
	3000K	A4	580		
80	3500K	A4	600		
80	4000K	A4	610		
	5000K	A4	610		
	5700K	A4	600		
	6500K	A4	600		

Notes:

- 1) Tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature
- 2) Samsung maintains measurement tolerance of: Luminous flux = ± 7 %, CRI = ± 1 , R9 = ± 6.5



2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
	_		147		_		_			•			_	_	_		

Digit	PKG Information	Code			Specification					
1 2 3	Samsung Package High Power	SPH	High Power PKG							
4 5	Color	WH	White `	White `						
6	Product Version	1	1st Version							
7 8	Form Factor	L5	5050 size							
9	Lens Type	N	No lens							
10	Model	6	5050 Series							
11	Internal Code	0								
12	CRI	3 Min. 70								
12	CRI	5	Min. 80							
42 44	5	XE	VE DiaI-	D1	23.5 – 24.5					
13 14	Forward Voltage (V)	XE	Bin code	E1	24.5 – 25.5					
		Υ	2200K							
		W	2700K							
		V	3000K							
15	CCT (II)	U	3500K							
15	CCT (K)	Т	4000K							
		R	5000K							
		Q	5700K							
		Р	6500K							
16	MacAdam Step	3	MacAdam 3-Ste	p						
10	iviacAuaiii Step	5	MacAdam 5-Ste	p						
17 18	Luminous Flux (lm)	A4	508C ECO							

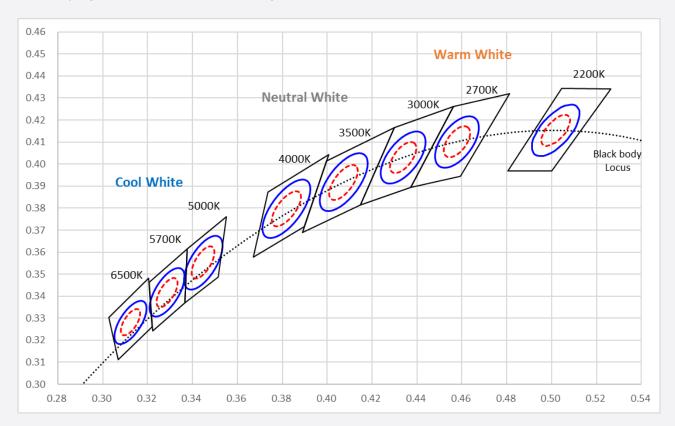
a) Luminous flux Rank (I_F = 160 mA, T_j = 25°C)

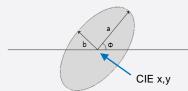
CRI (R _a)	Nominal		VE Dead	Chrom	Fl	XI	Flux Range
Min.	ССТ(К)	Product Code	VF Rank	Rank (Bins)	Rank	Bins	(Φv, lm)
	2200	SPHWH1L5N603XEY3A4		V2. VE		56	560-600
	2200	SPHWH1L5N603XEY5A4		Y3, Y5		60	600-640
	2700	SPHWH1L5N603XEW3A4		W3, W5		62	620-660
	2700	SPHWH1L5N603XEW5A4		W3, W3		66	660-700
	2000	SPHWH1L5N603XEV3A4		V2 VE		64	640-680
	3000	SPHWH1L5N603XEV5A4		V3, V5		68	680-720
	2500	SPHWH1L5N603XEU3A4		113 115		65	650-690
70	3500	SPHWH1L5N603XEU5A4	VE	U3, U5	A 4	69	690-730
70	4000	SPHWH1L5N603XET3A4	XE	тэ тс	A4	66	660-700
	4000	SPHWH1L5N603XET5A4		T3, T5		70	700-740
	F000	SPHWH1L5N603XER3A4		R3, R5		66	660-700
	5000	SPHWH1L5N603XER5A4				70	700-740
	F700	SPHWH1L5N603XEQ3A4		Q3, Q5		65	650-690
	5700	SPHWH1L5N603XEQ5A4		Q3, Q5		69	690-730
	6500	SPHWH1L5N603XEP3A4		D2 D5		64	640-680
	0300	SPHWH1L5N603XEP5A4		P3, P5		68	680-720
	2200	SPHWH1L5N605XEY3A4		V2 V5		47	470-510
		SPHWH1L5N605XEY5A4		Y3, Y5		51	510-550
	2700	SPHWH1L5N605XEW3A4		W2 W5		55	550-590
	2700	SPHWH1L5N605XEW5A4		W3, W5		59	590-630
	2000	SPHWH1L5N605XEV3A4		V2. V5		58	580-620
	3000	SPHWH1L5N605XEV5A4		V3, V5		62	620-660
	2500	SPHWH1L5N605XEU3A4		112 115		60	600-640
90	3500	SPHWH1L5N605XEU5A4	VF	U3, U5	A A	64	640-680
80	4000	SPHWH1L5N605XET3A4	XE	T2 T5	A4	61	610-650
	4000	SPHWH1L5N605XET5A4		T3, T5		65	650-690
	F000	SPHWH1L5N605XER3A4		D2 D5		61	610-650
	5000	SPHWH1L5N605XER5A4		R3, R5		65	650-690
	F700	SPHWH1L5N605XEQ3A4		03.05		60	600-640
	5700	SPHWH1L5N605XEQ5A4		Q3, Q5		64	640-680
	CE00	SPHWH1L5N605XEP3A4		D2 D5		60	600-640
	6500	SPHWH1L5N605XEP5A4		P3, P5		64	640-680

b) Voltage Bins ($I_F = 160 \text{ mA}, T_j = 25^{\circ}\text{C}$)

Nominal CCT (K)	CRI (R _a) Min.	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
			XE	D1	23.5 – 24.5
-	-	-	ΛE	E1	24.5 – 25.5

c) Chromaticity Region & Coordinates (I_F = 160 mA, T_j = 85°C)





CRI	ССТ	Rank	CIE x	CIE y	Ф	А	b
	2200K	Y3	0.5019	0.4153	49.3	0.0086	0.0040
	2200K	Y5	0.5019	0.4153	49.3	0.0144	0.0066
	2700K	W3	0.4578	0.4101	53.7	0.0081	0.0042
	2700K	W5	0.4378	0.4101	33.7	0.0135	0.0070
	3000K	V3	0.4338	0.4030	53.2	0.0083	0.0041
	3000K	V5	0.4556	0.4030	33.2	0.0138	0.0068
	3500K	U3	0.4073	0.3917	54.0	0.0093	0.0041
70	3300K	U5	0.4073	0.3917	54.0	0.0155	0.0069
80	4000K	T3	0.3818	0.3797	53.7	0.0094	0.0040
	4000K	T5	0.3616	0.3797	33.7	0.0157	0.0067
	5000K	R3	0.3447	0.3553	59.6	0.0082	0.0035
	3000K	R5	0.5447	0.5555	39.0	0.0137	0.0058
	5700K	Q3	0.3287	0.3417	59.1	0.0075	0.0032
	3700K	Q 5	0.3207	0.3417	33.1	0.0125	0.0053
	6500K	Р3	0.3123	0.3282	58.6	0.0067	0.0029
	JUUK	P5	0.3123	0.3202	30.0	0.0112	0.0048

Note : Samsung maintains measurement tolerance of: Cx, $Cy = \pm 0.005$

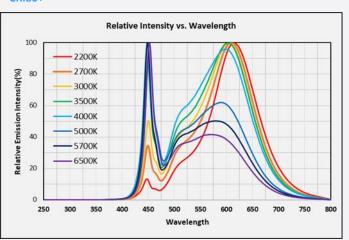
3. Typical Characteristic Graphs

a) Spectral Distribution ($I_F = 160 \text{ mA}, T_j = 25^{\circ}\text{C}$)

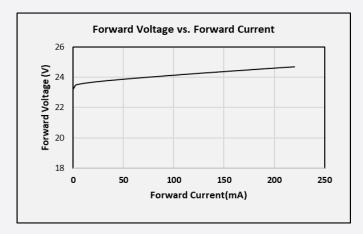
CRI70+

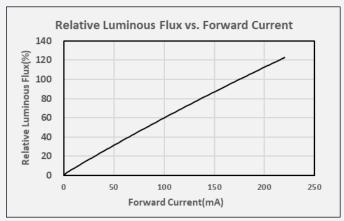
Relative Intensity vs. Wavelength 100 -2200K Relative Emission Intensity(%) 80 2700K 3000K 3500K 4000K 5000K 5700K 20 6500K 450 700 750 250 300 350 400 500 550 600 650 800 Wavelength

CRI80+

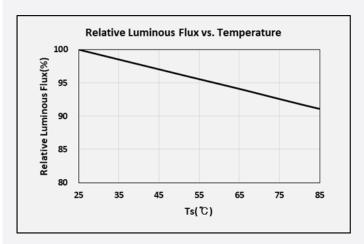


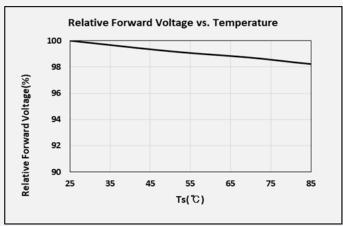
b) Forward Current Characteristics $(T_i = 25^{\circ}C)$



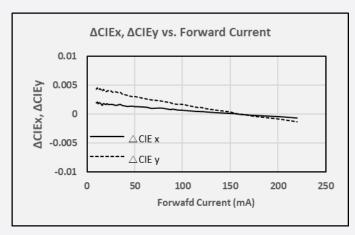


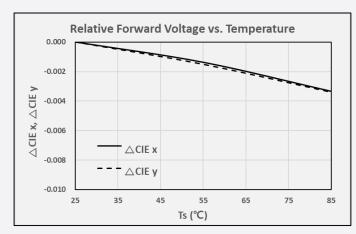
c) Temperature Characteristics (I_F = 160 mA)



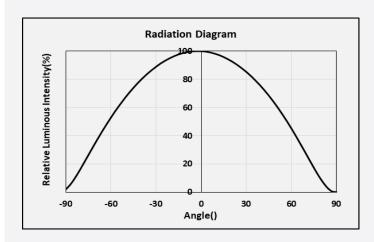


d) Color Shift Characteristics ($I_F = 160 \text{ mA}, T_j = 25^{\circ}\text{C}$)

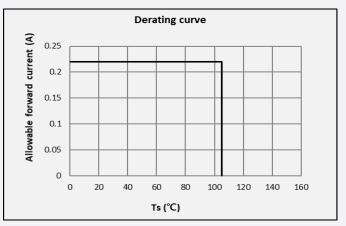




e) Beam Angle Characteristics ($I_F = 160 \text{ mA}, T_j = 25^{\circ}\text{C}$)

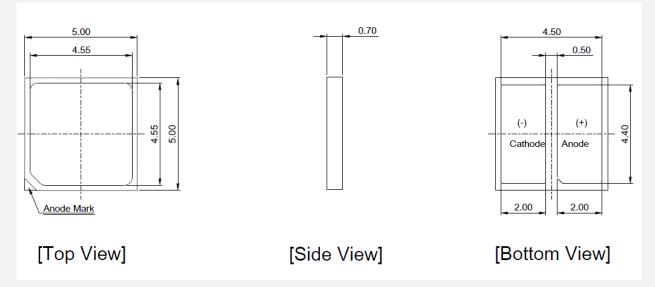


f) Derating Curve



4. Outline Drawing & Dimension

a) Mechanical Dimensions



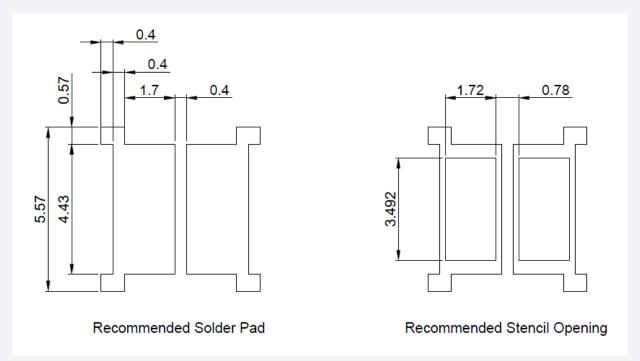
Notes:

1) Mark for the Anode

2) Unit: mm

3) Tolerance: ±0.1mm

b) Recommended Solder Pad



5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle
High Temperature Operating Life Test	85°C, 110mA	1000 h
Wet High Temperature Operating Life Test	85℃, 85 % RH, DC 110mA	1000 h
Temperature Cycling	-45°C / 15min ~ 125°C / 15min Temperature change within 5min	500 cycles
ESD (HBM)	R1: $10 \text{ M}\Omega$ R2: $1.5 \text{ k}\Omega$ C: 100 pF V: $\pm 8 \text{ kV}$	5 times
Vibration Test	20 $^{\sim}$ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 $^{\sim}$ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times

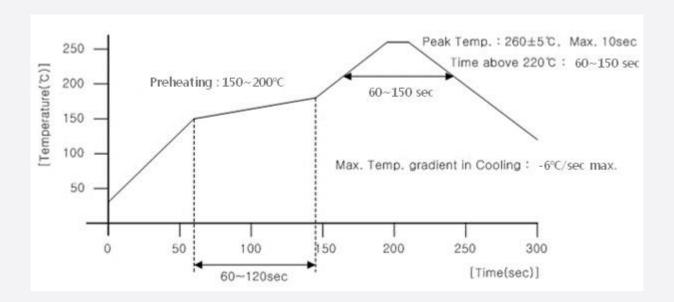
b) Criteria for Judging the Damage

Item	Symbol	Test Condition	Limit				
item	Symbol	(T _c = 25°C)	Min.	Max.			
Forward Voltage	V_{F}	I _F = Sorting Current	L.S.L. * 0.9	U.S.L. * 1.1			
Luminous Flux	Фи	I _F = Sorting Current	L.S.L * 0.7	U.S.L * 1.3			

6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



b) Manual Soldering Conditions

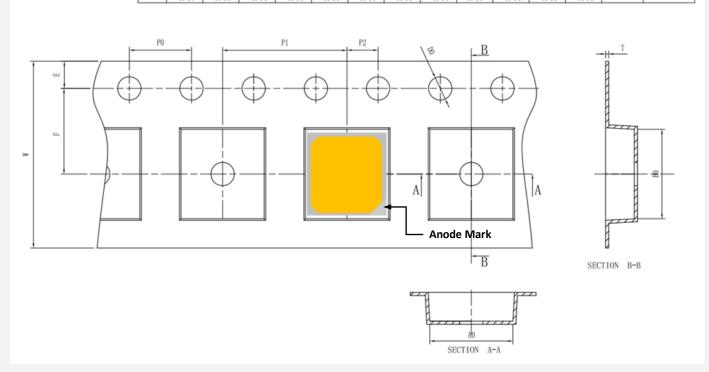
Not more than 5 seconds @ max. 300℃, under soldering iron.

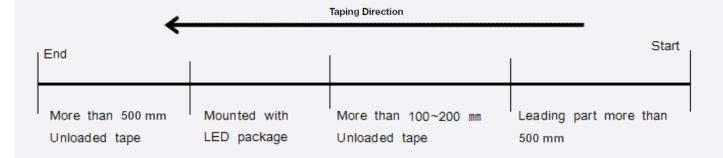
7. Tape & Reel

a) Taping Dimension

(unit: mm)

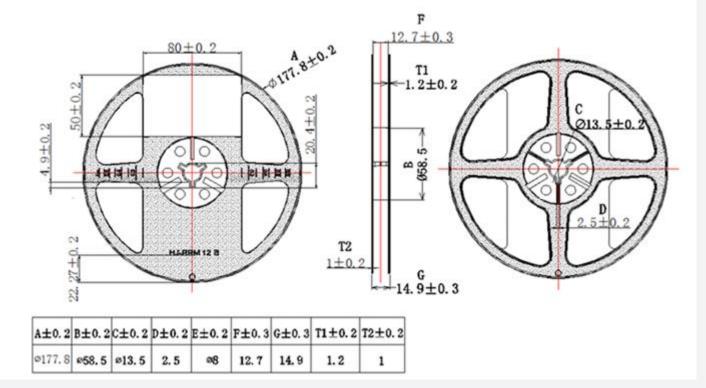
_															
	ITEM	W	A0	B0	КО	Е	F	D0	D1	P0	P1	P2	T		
	DIM	12.00	5. 40	5. 20	0.95	1.75	5. 50	1.50	1.50	4.00	8.00	2.00	0.20	LENGTH	PCS/REEL
	5. 35	+0.10	+0.05 -0.05	+0. 05 -0. 05	+0.05	+0.10	+0.10	+0.10	+0.10	+0.10	+0.10	+0.10	+0.05	m	PCS





b) Reel Dimension (max 2,000 pcs)

(unit: mm)

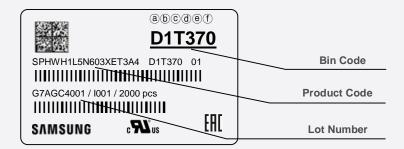


Notes:

- 1) Quantity: The quantity/reel is 2000 pcs
- 2) All dimensions are millimeters.
- 3) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag.

8. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 4)

Bin Code:

(a) (b): Forward Voltage bin (refer to page 6)(c) (d): Chromaticity bin (refer to page 7)(e) (f): Luminous Flux bin (refer to page 5)

b) Lot Number

The lot number is composed of the following characters:



123456789/Iabc / xxxx pcs

(1) 2 : Production site (G7 : Guangzhou ,China)

3 : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

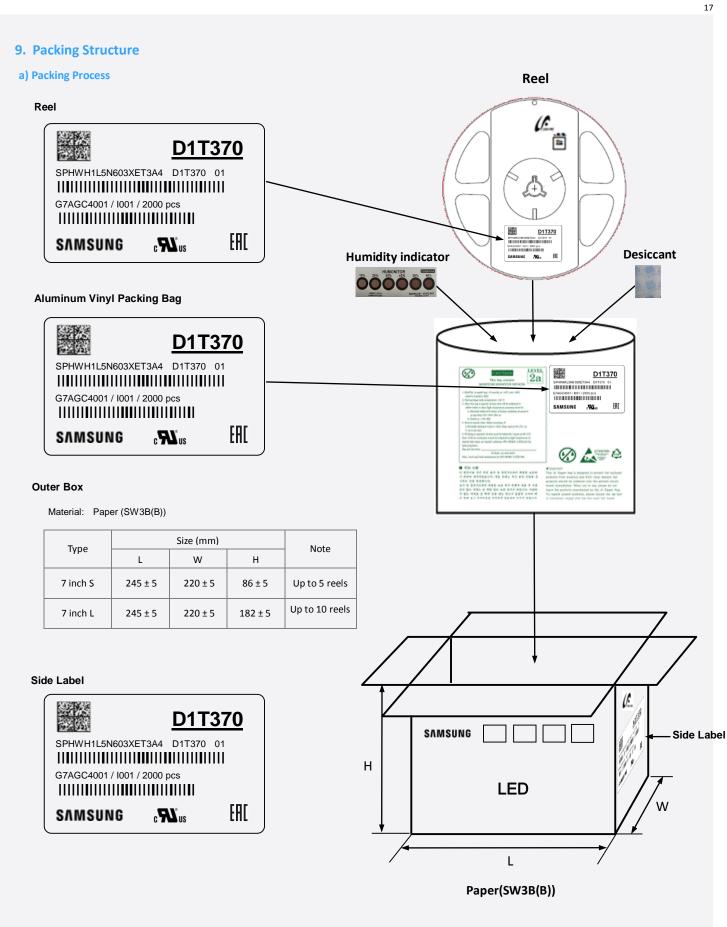
(4) : Year (G:2022, H:2023 ...)

(5) : Month (1-9, A, B, C)

6 : Day (1-9, A, B-V)

789 : Samsung Electronics Product serial number (001 - 999)

(a) (b) (c) : Reel number(001 - 999)



b) Aluminum Vinyl Packing Bag



CAUTION



This bag contains MOISTURE SENSITIVE DEVICES

- Shelf life in sealed bag: 12 months at <40°C and <90% relative humidity (RH)
- 2. Peak package body temperature: 240 °C
- After this bag is opened, devices that will be subjected to reflow solder or other high temperature processes must be-
 - a. Mounted within 672 hours at factory conditions of equal to or less than 30°C /60% RH, or
 - b. Stored at < 10% RH
- 4. Devices require bake, before mounting, if:
 - a. Humidity Indicator Card is >/60% when read at 23 \pm 5°C, or b. 2a is not met.
- 5. If baking is required, devices must be baked for 10 ~ 24 hours at 60±5°C Note: if device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC J-STD-033 for bake procedure.

Bag seal due date: ____

(I blank, see code label)

Note: Level and body temperature by IPC/JEDEC J-STD-020



D1T370

SPHWH1L5N603XET3A4 D1T370 01

G7AGC4001 / I001 / 2000 pcs

SAMSUNG

c**SU**us

FAI









■ 주의 사항

이 알루미늄 지퍼 백은 습기 및 정전기로부터 제품을 보호하 기 위하여 제작되었습니다. 개봉 후에는 즉시 솔더 작업을 설 시하는 것을 권장합니다.

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■ Important

This Al Zipper bag is designed to protect the enclosed products from moisture and ESD. Once opened, the products should be soldered onto the printed circuit board immediately. When not in use, please do not leave the products unprotected by the Al Zipper Bag. To repack unused products., please ensure the zip-lock is completely sealed with the dry pack left inside.

c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag

(This image is for reference only. Silicagel and humidity indicator shapes may be different.)





10. Precautions in Handling & Use

- 1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. Shelf life of sealed bags is 12 months at temperature 0~40℃, 0~90 % RH.
- 5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30℃ / 60 % RH, or
 - b. Stored at <10 % RH
- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at $23 \pm 5^{\circ}$ C
- 8) Devices must be baked for 1 hour at $60 \pm 5^{\circ}$ C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) Risk of sulfurization (or tarnishing)
 - The LED from Samsung Electronics Co., Ltd. uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as: rubber, plain paper, lead solder cream, etc.



Legal and additional information.

About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors.

We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

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